

# RJH1CD5DPQ-E0

1200V - 20A - IGBT Application: Inverter

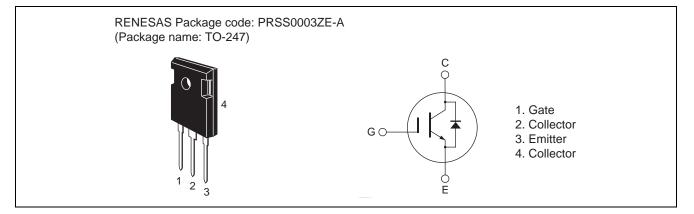
R07DS0517EJ0400 Rev.4.00 Jan 19, 2012

# Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)} = 2.0 \text{ V}$  typ. (at  $I_C = 20 \text{ A}$ ,  $V_{GE} = 15 \text{ V}$ ,  $Ta = 25^{\circ}\text{C}$ )
- Built-in fast recovery diode ( $t_{rr} = 200$  ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 100$  ns typ. (at  $V_{CC} = 600$  V,  $V_{GE} = 15$  V,  $I_C = 20$  A, Rg = 5  $\Omega$ ,  $Ta = 25^{\circ}C$ , inductive load)

## Outline



## **Absolute Maximum Ratings**

				$(Ta = 25^{\circ}C)$
Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	1200	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	$Tc = 25^{\circ}C$	Ι <sub>C</sub>	40	A
	Tc = 100°C	Ι <sub>C</sub>	20	A
Collector peak current		ic(peak) Note1	60	A
Collector to emitter diode forward current		I <sub>DF</sub>	20	A
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) <sup>Note1</sup>	60	A
Collector dissipation		Pc <sup>Note2</sup>	260.4	W
Junction to case thermal resistance (IGBT)		θj-c <sup>Note2</sup>	0.48	°C/ W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at Tc = 25°C



di<sub>F</sub>/dt = 100 A/μs

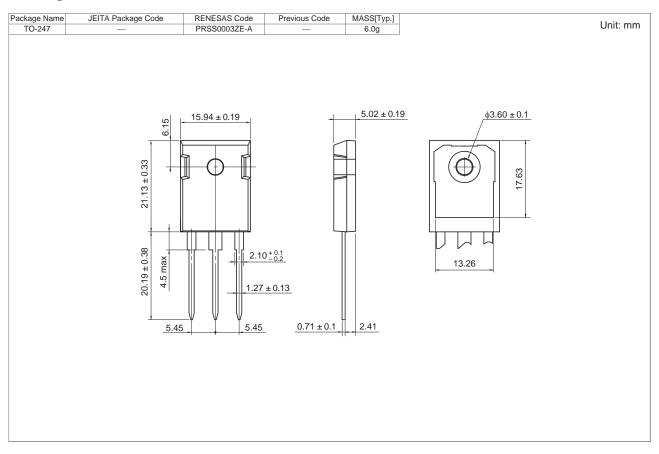
# **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$	
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I <sub>CES</sub> /I <sub>R</sub>	—	—	5	μΑ	$V_{CE} = 1200 \text{ V}, \text{ V}_{GE} = 0$	
Gate to emitter leak current	I <sub>GES</sub>	—	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	V <sub>GE(off)</sub>	4	—	8	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	2.0	_	V	$I_{C} = 20 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1100	_	pF	$V_{CE} = 25 V$ $V_{GE} = 0$ $f = 1 MHz$	
Output capacitance	Coes	_	40	_	pF		
Reveres transfer capacitance	Cres	_	25	_	pF		
Switching time	t <sub>d(on)</sub>		40		ns	$V_{CC} = 600 \text{ V}, \text{ V}_{GE} = 15 \text{ V}$ $I_C = 20 \text{ A}$ $\text{Rg} = 5 \Omega$ Inductive load	
	tr	_	15	_	ns		
	t <sub>d(off)</sub>	_	90	_	ns		
	t <sub>f</sub>	_	100	_	ns		
Short circuit withstand time	t <sub>sc</sub>	—	5	—	μs	$\label{eq:Vcc} \begin{split} V_{CC} &\leq 720 \ V, \ V_{GE} = 15 \ V \\ Tc &\leq 125^{\circ}C \end{split}$	
	·		·			-	
FRD forward voltage	V <sub>F</sub>	—	1.7	_	V	$I_F = 20 \text{ A}^{\text{Note3}}$	
FRD reverse recovery time	t <sub>rr</sub>	—	200	—	ns	I <sub>F</sub> = 20 A di <sub>F</sub> /dt = 100 A/μs	

Notes: 3. Pulse test.



### **Package Dimension**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container	
RJH1CD5DPQ-E0#T2	450 pcs	Box (Tube)	



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